

SYLVANIA CRYSTAL DIODES

SYLVANIA ELECTRONIC TUBES 1S

			MAXIMUM RATINGS AT 25° C				CHARACTERISTICS AT 25° C				
TYPE	DESCRIPTION	AMBIENT TEMPERATURE RANGE (0°C)	CONTINUOUS REVERSE WORKING VOLTAGE (VOLTS)	RECURRENT PEAK ANODE CURRENT (MA.)	AVERAGE ANODE CURRENT (MA.)	SURGE CURRENT (MA. 1 SEC.)	PEAK REVERSE VOLTAGE FOR ZERO DYNAMIC RESISTANCE (VOLTS MIN.)	FORWARD CURRENT AT +1 VOLT (MA. MIN.)	REVERSE CURRENT (μA MAX.)	FORWARD RESISTANCE AT +1 VOLT (OHMS MAX.)	REVERSE RESISTANCE (OHMS MIN.)
IN34	General Purpose Diode	-50 to +75	60	150	50	500	75	5	30@-10V, 500@-50V	200	333K@-10V, 100K@-50V
IN34A	General Purpose Diode	-55 to +75	60	150	50	500	75	5	30@-10V, 500@-50V	200	330K@-10V, 100K@-50V
IN35	Matched Duo-Diode (Note 1)	-50 to +75	50	60	22.5	100	75	7.5	10@-10V	133	1.0 meg.@-10V
IN38	100 Volt Diode	-50 to +75	100	150	50	500	120	4	6@-3V, 500@-100V	250	500K@-3V, 200K@-100V
IN38A	100 Volt Diode	-55 to +75	100	150	50	500	120	4	6@-3V, 500@-100V	250	500K@-3V, 200K@-100V
IN39	200 Volt Diode	-50 to +75	200	150	50	500	225	3.0	100@-100V, 600@-200V	333	1Meg.@-100V, 333K@-200V
IN39A	200 Volt Diode (Glass)	-50 to +75	200	150	50	500	225	3.0	100@-100V, 600@-200V	333	1Meg.@-100V, 333K@-200V
IN40	General Purpose Varistor (Note 2)	-50 to +75	25	60	22.5	100	75	12.75@1.5V	35@-10V	118@1.5V	285K@-10V
IN41	General Purpose Varistor (Note 2)	-50 to +75	25	60	22.5	100	75	12.75@1.5V	40@-10V	118@1.5V	250K@-10V
IN42	100 Volt Varistor (Note 2)	-50 to +75	100	60	22.5	100	120	12.75@1.5V	800@-100V	118@1.5V	125K@-10V
IN54	High Back Resistance Diode	-50 to +75	50	150	50	500	75	5	7@-10V, 100@-50V	200	1.4 Meg.@-10V, 500K@-50V

SYLVANIA CRYSTAL DIODES Cont'd

		MAXIMUM RATINGS AT 25° C					CHARACTERISTICS AT 25° C				
TYPE	DESCRIPTION	AMBIENT TEMPERATURE RANGE (0°C)	CONTINUOUS REVERSE WORKING VOLTAGE (VOLTS)	RECURRENT PEAK ANODE CURRENT (MA.)	AVERAGE ANODE CURRENT (MA.)	SURGE CURRENT (MA. 1 SEC.)	PEAK REVERSE VOLTAGE FOR ZERO DYNAMIC RESISTANCE (VOLTS MIN.)	FORWARD CURRENT AT +1 VOLT (MA. MIN.)	REVERSE CURRENT (μ A MAX)	FORWARD RESISTANCE AT +1 VOLT (OHMS MAX.)	REVERSE RESISTANCE (OHMS MIN.)
IN54A	High Back Resistance Diode	-50 to +75	50	150	50	500	75	5	7@-10V, 100@-50V	200	1.4 Meg.@-10V, 500K@-50V
IN55	150 Volt Diode	-50 to +75	150	150	50	500	170	4	500@-100V	250	300K@-150V
IN55A	150 Volt Diode	-50 to +75	150	150	50	500	170	4	500@-150V	250	300K@-150V
IN56	High Conduction Diode	-50 to +75	40	200	60	1000	50	15	300@-30V	67	100K@-30V
IN56A	High Conduction Diode	-50 to +75	40	200	60	1000	50	15	300@-30V	67	100K@-30V
IN58	100 Volt Diode	-50 to +75	100	150	50	500	120	4	600@-100V	250	167K@-100V
IN58A	100 Volt Diode	-50 to +75	100	150	50	500	120	4	600@-100V	250	167K@-100V
IN59	250 Volt Diode	-50 to +75	260	150	50	500	275	3.0	800@-250V	333	300K@-250V
IN59A	250 Volt Diode (Glass)	-50 to +75	260	150	50	500	275	3.0	800@-250V	333	300K@-250V
IN60	Video Detector Diode	-50 to +75	25	150	50	500	30	Note 3	Note 4	150K (Note 4)
IN63	High Back R Diode	-50 to +75	100	150	50	400	125	4.0	50@-50V	250	1 Meg.@-50V
IN65	General Purpose Diode	-50 to +75	70	150	50	400	2.5	200@-50V	400	250K@-50V

SYLVANIA CRYSTAL DIODES Cont'd

SYLVANIA ELECTRONIC TUBES 35

TYPE	DESCRIPTION	AMBIENT TEMPERATURE RANGE (0°C)	MAXIMUM RATINGS AT 25° C				CHARACTERISTICS AT 25° C				
			CONTINUOUS REVERSE WORKING VOLTAGE (VOLTS)	RECURRENT PEAK ANODE CURRENT (MA.)	AVERAGE ANODE CURRENT (MA.)	SURGE CURRENT (MA. 1 SEC.)	PEAK REVERSE VOLTAGE FOR ZERO DYNAMIC RESISTANCE (VOLTS MIN.)	FORWARD CURRENT AT +1 VOLT (MA. MIN.)	REVERSE CURRENT (μA MAX.)	FORWARD RESISTANCE AT +1 VOLT (OHMS MAX.)	REVERSE RESISTANCE (OHMS MIN.)
IN67	High Back Resistance Diode	-50 to +75	80	100	35	500	100	4.0	5@-5V, 50@-50V	250	1 Meg.@-5V, 1 Meg.@-50V
IN69	General Purpose Diode	-55 to +75	60	125.	40	400	75	5	50@-10V, 850@-50V	200	200K@-10V, 588K@-50V
IN70	100 Volt Diode	-50 to +70	100	90	30	350	125	3.0	300@-50V, 25@-10V	333	166K@-50V, 400K@-10V
IN71	Low Impedance Varistor (Note 5)	-50 to +75	40	200	60	1000	50	15	300@-30V	67	100K@-30V
IN77A	Photo Diode	Operating Voltage = 50V. D C Max.; Ambient Temp. = 50°C Max.; Dissipation (25°C) = 20 Mw Max.; Reverse Current—Dark (Eb = -50V. D C) = 200 μa D C Max.; Reverse Current—Dark (Eb = -10V. D C) = 50 μa D C Max.; Noise Voltage—Dark (Eb = -45V. D C, RL = 100,000 Ohms) = 15 Mv RMS Max.; Light Sensitivity (RL = 100,000 Ohms) = 5V. Min. Peak to Peak. Operation in the Visible and Infra-Red Spectrum.									
IN81	High Back Resistance Diode	-55 to +75	40	90	30	350	50	3	10@-10V	333	1.0 Meg.@-10V
IN82	U H F Mixer Diode	-50 to +75	Note 6
IN82A	U H F Mixer Diode	-50 to +75	Note 6
IN105	Video Detector Diode	-50 to +75	25	150	50	500	75	Note 3	Note 4	150K (Note 4)
IN109	Harmonic Generator Diode	-50 to +75	15	150	50	500	75	Note 7
IN111	Computer Diode	-50 to +75	60	150	25	500	75	5	Note 8	200	400K@55°C (Note 8)

SYLVANIA CRYSTAL DIODES Cont'd

			MAXIMUM RATINGS AT 25° C				CHARACTERISTICS AT 25° C				
TYPE	DESCRIPTION	AMBIENT TEMPERATURE RANGE (0°C)	CONTINUOUS REVERSE WORKING VOLTAGE (VOLTS)	RECURRENT PEAK ANODE CURRENT (MA.)	AVERAGE ANODE CURRENT (MA.)	SURGE CURRENT (MA. 1 SEC.)	PEAK REVERSE VOLTAGE FOR ZERO DYNAMIC RESISTANCE (VOLTS MIN.)	FORWARD CURRENT AT +1 VOLT (MA. MIN.)	REVERSE CURRENT (µa MAX.)	FORWARD RESISTANCE AT +1 VOLT (OHMS MAX.)	REVERSE RESISTANCE (OHMS MIN.)
IN112	Computer Diode	-50 to +75	60	150	25	500	75	5	Note 8	200	200K@55°C (Note 8)
IN113	Computer Diode	-50 to +75	60	150	25	500	75	2.5	Note 8	400	400K@55°C (Note 8)
IN114	Computer Diode	-50 to +75	60	150	25	500	75	2.5	Note 8	400	200K@55°C (Note 8)
IN115	Computer Diode	-50 to +75	60	150	25	500	75	2.5	Note 8	400	100K@55°C (Note 8)
IN119	Computer Diode	-50 to +75	60	150	25	500	75	5	Note 8	200	400K@55°C (Notes 8 & 9)
IN120	Computer Diode	-50 to +75	60	150	25	500	75	5	Note 8	200	200K@55°C (Notes 8 & 9)
IN132	Video Detector Diode	-50 to +75	25	150	50	500	30	Note 10	Note 4	150K (Note 4)
IN172	U H F Mixer Diode	-50 to +75	Note 6
IN193	Hi Temp. Computer Diode	to 150 Note 10	40@150°C	50	30	100	1.0@+2 Volts	40@-40V	Min. Forward Current @ 2 Volts = 1.5 Ma. @ 150°C Max. Reverse Current @ -40 Volts = 500 µa @ 150°C	
IN194	Hi Temp. Computer Diode	to 150 Note 10	40@150°C	50	30	100	1.5@+2 Volts	60@-40V	Min. Forward Current @ 2 Volts = 2.0 Ma. @ 150°C Max. Reverse Current @ -40 Volts = 600 µa @ 150°C	

SYLVANIA CRYSTAL DIODES Cont'd

			MAXIMUM RATINGS AT 25° C				CHARACTERISTICS AT 25° C				
TYPE	DESCRIPTION	AMBIENT TEMPERATURE RANGE (0°C)	CONTINUOUS REVERSE WORKING VOLTAGE (VOLTS)	RECURRENT PEAK ANODE CURRENT (MA.)	AVERAGE ANODE CURRENT (MA.)	SURGE CURRENT (MA. 1 SEC.)	PEAK REVERSE VOLTAGE FOR ZERO DYNAMIC RESISTANCE (VOLTS MIN.)	FORWARD CURRENT AT +1 VOLT (MA. MIN.)	REVERSE CURRENT (μA MAX)	FORWARD RESISTANCE AT +1 VOLT (OHMS MAX.)	REVERSE RESISTANCE (OHMS MIN.)
IN195	Hi Temp. Computer Diode	to 150 Note 10	40@150°C	50	30	100	2.0@+2 Volts	80@-40V	Min. Forward Current @ 2 Volts = 3.5 Ma. @ 150°C Max. Reverse Current @ -40 Volts = 700 μA @ 150°C	
IN196	Hi Temp. Short Recovery Time	to 150 Note 10	40@150°C	50	30	100	1.0@+2 Volts	40@-40V	Min. Forward Current @ 2 Volts = 1.5 Ma. @ 150°C Max. Reverse Current @ -40 Volts = 500 μA @ 150°C	

Note 1—Units are matched in the forward direction at 1 volt so that the current flowing through the lower resistance unit is within 10% of that through the higher resistance unit. Ratings are shown for each diode.

Note 2—Consists of four specially selected and matched diodes whose resistances are balanced within ±2.50% in the forward direction at 1.5 volts. For additional balance, the forward resistance of each varistor pair is matched to within three ohms. Ratings shown are for each diode.

Note 3—Units are tested in a circuit employing an input of 1.6 volts rms at 40 MC, 75% modulated at 400 cycles. Demodulated output across a 4700 ohm resistor shunted by a 5 μμf capacitor is a minimum of 1.55 volts peak to peak.

Note 4—Minimum specified reverse resistance applies to all points between 0 and -10 volts with 60 cps sweep.

Note 5—Consists of four specially selected diodes whose forward currents are matched within a range of 1 ma. with 1 volt applied. Ratings shown are for each diode.

Note 6—The 1N82, 1N82A, and 1N172 are low noise and low conversion loss UHF television mixer crystals. The noise factor of the 1N82 is 16 db max., that of the 1N82A is 14 db max. The noise factor is measured at 700 mc with a local oscillator drive (bias current) of 0.5 ma.

Note 7—Units are tested in a circuit employing a fundamental frequency of 126 MC. The rectified 3rd harmonic output is 0.5 ma. minimum.

Note 8—Minimum specified reverse resistance applies at 55°C for all points between -10V and -50V with 60 cps sweep.

Note 9—Reverse recovery time for these units is specified and defined as the time required for the diode to recover to a given reverse current when the operating voltage necessary to give 30 ma forward conduction is rapidly switched to -35 volts.

Note 10—Same as note 9 with 5 Ma forward current to -35 volts.

Type	Reverse Current μA	Reverse Resistance Ohms	Recovery Time μsec.
IN119	700	50 K	0.5
	82.5	400 K	3.5
IN120	700	50 K	0.5
	175	200 K	3.5
IN193	400	0.5
IN194	400	0.5
IN195	400	0.5
IN196	100	0.1

Note 11—Units are tested in a circuit employing an input of 0.1 volts RMS at 44 Mc. Rectified output is a minimum of 140 μA with a 3600 ohm load and 65μh shunted by 5 μμf capacitor.

Note 12—Normally supplied with 1/2" minimum leads, but will be supplied without leads for clip-in applications upon request. The polarity of all Sylvania crystals is indicated by a graphic symbol on the body. The cathode side is indicated by a color band and the label "cath."

CRYSTAL DIODE REPLACEMENT GUIDE

This chart must be read from left to right. That is, the diode in question must be located in the left hand column and its replacement found in the right hand column.

The Sylvania replacement types are electrical replacements only — in some cases mechanical differences exist. However, for those types designed for clip-in or plug-in applications, the replacement is also mechanically equivalent.

Only the manufacturer who registered the type number with RETMA is listed, although several types are manufactured by more than one company.

ABBREVIATIONS OF MANUFACTURERS

SYL—SYLVANIA
CBS-HY—CBS-HYTRON
WE—WESTERN ELECTRIC
RR—RADIO RECEPTOR
GE—GENERAL ELECTRIC
HA—HUGHES AIRCRAFT

RAY—RAYTHEON
TP—TRANSISTOR PRODUCTS
AMP—AMPEREX
LAN—LANSDALE
IR—INTERNATIONAL RECTIFIER
NU—NATIONAL UNION

TYPE	DESIGNATION	DESIGNED FOR	MANUFACTURER	SYLVANIA REPLACEMENT
1N34 1N34A		General Purpose Use General Purpose Use	SYL SYL	1N34A, 1N54, 1N54A 1N54A, 1N58A, 1N38A, 1N55A
1N35 1N38 1N38A		Matched Duo-Diode 100 Volt Working Voltage 100 Volt Working Voltage	SYL SYL SYL	1N35 1N38A, 1N55, 1N55A 1N55A, 1N63, 1N67
1N39 1N39A 1N40 1N41 1N42		200 Volt Working Voltage 200 Volt Working Voltage General Purpose Varistor Use General Purpose Varistor Use 100 Volt Varistor	SYL CBS-HY SYL SYL SYL	1N59 1N39, 1N59 1N42, 1N41 1N42, 1N40 1N42
1N43 1N44 1N45 1N46 1N47		General Purpose Use General Purpose Use General Purpose Use General Purpose Use General Purpose Use	WE WE WE WE WE	1N34, 1N34A 1N58, 1N58A 1N34 1N34, 1N34A 1N38, 1N38A
1N48 1N51 1N52	G5 G5C G5D	General Purpose Use General Purpose Use General Purpose Use	GE GE GE	1N34, 1N34A 1N34, 1N34A 1N38, 1N38A, 1N58, 1N58A
1N54 1N54A		High Back Resistance High Back Resistance	SYL SYL	1N54A, 1N81 1N81
1N55 1N55A 1N55B 1N56 1N56A		150 Volt Working Voltage 150 Volt Working Voltage 150 Volt Working Voltage High Conduction High Conduction	SYL SYL HA SYL SYL	1N55A, 1N39, 1N59 1N39, 1N59 1N55A 1N56A 1N56A
1N57		(Obsolete Type)	SYL	1N58, 1N58A, 1N38, 1N38A
1N58 1N58A 1N59 1N60		100 Volts Working Voltage 100 Volts Working Voltage 250 Volts Working Voltage Video Detector	SYL SYL SYL SYL	1N58, 1N55, 1N55A 1N38A, 1N55A 1N59 1N60
1N63 1N64 1N65	G5E G5G	General Purpose Use Video Detector General Purpose Use	GE GE GE	1N63, 1N38A 1N60, 1N132 1N38, 1N38A, 1N58, 1N58A
1N66 1N67		General Purpose Use 50 Volt DC Restorer	RAY RAY	1N34, 1N34A 1N67
1N67A 1N68 1N68A 1N69 1N70	G5K G5L	High Back Resistance 100 Volt DC Restorer High Peak Voltage General Purpose Use General Purpose Use	HA RAY HA GE GE	1N67, 1N38A 1N38, 1N38A 1N58A 1N69, 1N34A 1N70, 1N38, 1N38A, 1N58A
1N71 1N72 1N73 1N74 1N75	G7 G9 G9A G5M	Low Impedance Varistor UHF Mixer General Purpose Varistor Use General Purpose Varistor Use General Purpose Varistor Use	SYL GE GE GE GE	1N71 1N82A 1N40 1N40 1N39, 1N63, 1N67
1N77 1N77A 1N81 1N82 1N82A	G5P	(Obsolete Type) Photodiode General Purpose Use UHF Mixer UHF Mixer	SYL SYL GE SYL SYL	1N77A 1N77A 1N81, 1N54A 1N82A, 1N172 1N82A

CRYSTAL DIODE REPLACEMENT GUIDE (Cont'd)

TYPE	DESIGNATION	DESIGNED FOR	MANUFACTURER	SYLVANIA REPLACEMENT
1N86 1N87 1N88 1N89 1N90		General Purpose Use Video Detector DC Restorer High Back Resistance General Purpose Use	AMP AMP AMP HA HA	1N34, 1N34A 1N60, 1N132 1N38, 1N38A 1N38A 1N34, 1N34A
1N105 1N109 1N110 1N111 1N112		Video Detector Harmonic Generator UHF Mixer Computer Application Computer Application	SYL SYL RR CBS-HY CBS-HY	1N105 1N109 1N82, 1N82A 1N111, 1N119 1N112, 1N120
1N113 1N114 1N115 1N116 1N119		Computer Application Computer Application Computer Application High Back Resistance Computer Application	CBS-HY CBS-HY CBS-HY HA SYL	1N113 1N114 1N115 1N54A 1N119
1N120 1N124 1N124A 1N126 1N127		Computer Application UHF Mixer UHF Mixer General Purpose Use 100 Volts Working Voltage	SYL LAN LAN HA HA	1N120 1N82A, 1N172 1N82A, 1N172 1N34, 1N34A 1N38, 1N38A
1N128 1N132 1N133 1N135 1N147		High Back Resistance Video Detector UHF Mixer General Purpose Use UHF Mixer	HA SYL CBS-HY CBS-HY LAN	1N54, 1N54A 1N60 1N82A, 1N172 1N34, 1N34A 1N82A, 1N172
1N172	CK705 CK705A CK706 CK707	UHF Mixer General Purpose Use General Purpose Use Video Detector 50 Volt DC Restorer	SYL RAY RAY RAY RAY	1N82A, 1N172 1N34, 1N34A 1N54A 1N60 1N38A, 1N67
	CK708 CK709 CK710 CK711 CK713	100 Volt DC Restorer General Purpose Varistor UHF Converter High Voltage Varistor Computer Application	RAY RAY RAY RAY RAY	1N38, 1N38A, 1N58A 1N40, 1N41 1N82, 1N82A 1N42 1N112
	CK715 G7A G7 G7E G7D	Frequency Multiplier UHF Mixer UHF Mixer Frequency Multiplier Frequency Multiplier	RAY GE GE GE GE	1N109 1N82 1N82 1N109 1N109
	G8A G7F G7G G1CA G1HA	Matched Duo-Diode Detector and Meter Rectifier Detector and Meter Rectifier Magnetic Amplifier Use Magnetic Amplifier Use	GE GE GE IR IR	1N35 1N105 1N60 1N38A 1N34A
	NU34 NU38 NU39 NU58 TP-34A	Computer Application (65V) 100 Volt Working Voltage 200 Volt Working Voltage 100 Volt Working Voltage General Purpose Use	NU NU NU NU TP	1N34 1N38 1N39, 1N59 1N58 1N34A
	TP-38A TP-39 TP-52 TP-55 TP-55A	General Purpose Use General Purpose Use General Purpose Use General Purpose Use General Purpose Use	TP TP TP TP TP	1N38A 1N39 1N38A 1N55A 1N55A
	TP-63 X-16 X-18	General Purpose Use Frequency Multiplier Video Detector	TP TP TP	1N38A 1N109 1N60

SPECIAL PURPOSE TUBES—VOLTAGE REGULATORS

TYPE	TYPICAL APPLICATION	CONSTRUCTION		MINIMUM STARTING VOLTAGE*	MINIMUM STARTING VOLTAGE°	OPERATING VOLTAGE APPROX.	MINIMUM OPERATING CURRENT MA.	MAXIMUM OPERATING CURRENT MA.	REGULATION VOLTS
		BASE	STYLE						
OA2	Voltage Regulator	5B0	T5½	156	185	150	5.0	30	2.0
OA3/VR75	Voltage Regulator	4AJ	ST-12	100	105	75	5.0	40	5.0
OB2	Voltage Regulator	5B0	T-5½	115	133	105	5.0	30	1.0
OB3/VR90	Voltage Regulator	4AJ	ST-12	105	130	90	5.0	30	5.0
OC3/VR105	Voltage Regulator	4AJ	ST-12	115	133	105	5.0	40	2.0
OD3/VR150	Voltage Regulator	4AJ	ST-12	160	185	150	5.0	40	4.0
1236A	Emission Limited Diode	1236A	Lock-In	RATINGS: $E_f = 3.0$ Volts Max. (A C or D C); $E_b = 1400$ Volts Max. RMS; D C Current = 4.0 Ma Max.; Plate Dissipation = 0.75 Watts. OPERATION: $E_f = 1.9$ V.; $I_f = .450$ Amp.; $E_b = 300$ V.; $I_b = 0.47$ Ma; Plate Load Resistance = 0.25 Megohm.					
1265	Voltage Regulator	4AJ	ST-12	135	...	90	5.0	30	...

* Average Values.

° Maximum Value of Manufacturing Limits.

SPECIAL PURPOSE TUBES—GAS CONTROL TYPES

TYPE	CLASS	CONSTRUCTION		EMITTER			MAXIMUM INVERSE ANODE VOLTAGE	MAXIMUM PEAK FORWARD ANODE VOLTAGE	MAXIMUM PEAK CATHODE CURRENT MA	MAXIMUM AVERAGE CATHODE CURRENT MA	MAXIMUM SURGE CURRENT AMPS.	GRID NO. 1 CIRCUIT RESISTANCE MEG.	ANODE SUPPLY VOLTAGE	ANODE VOLTAGE DROP	SCREEN OR SHIELD GRID VOLTAGE	CONTROL GRID BIAS VOLTAGE	LOAD RESISTANCE
		STYLE	BASE DIAG.	TYPE	VOLTS	AMP.											
0A4G	Triode	ST-12	4V	Cold K	100	25	105 130	70 70	Peak Grid No. 1 Voltage to Start A C= 70 V, R F = 55 V		
0A5	Pentode	T-5½	0A5	Cold K	Anode Voltage = 750 V. Grid 3 (Trigger) Grid Bias = +90 V. Grid No. 1 (Keep Alive) Current = 50 μa Discharge Cap. = 0.25 μf. Grid 3 (Trigger) Pulse Voltage = 95 V. Grid 3 (Trigger) Resistance = .25 Meg. Grid No. 2 Floating.										
2A4G	Triode	ST-12	5S	Fil.	2.5	2.5	200	200	1250	100	Max. Peak Voltage = 250 V.			15			
2D21	Tetrode	T-5½	7BN	Cath.	6.3	0.60	1300	650	500	100♦	10	1.0 1.0	117 400	8.0 8.0	0 0	*5.0 V. RMS -6.0 V. D C	1200 2000
6D4	Triode	T-5½	5AY	Cath.	6.3	0.25	Max. Voltage Between Elements = 450 V.		100	25♦	125 50	18 18	Grid No. 1 Voltage to Start = -12 V. Grid No. 1 Voltage to Start = -6 V.		
884	Triode	ST-12	6Q	Cath.	6.3	0.60	300♦	0.5 Max.	300	16	-30 V. D C
885	Triode	ST-12	5A	Cath.	2.5	1.5	Same as Type 884.										
2050	Tetrode	ST-12	6BS	Cath.	6.3	0.60	360 1300	180 650	1000♦ 1000♦	200 100	10 * 10 *	1.0 1.0	117 400	8 8	0 0	*5.0 V. RMS -6.0 V. D C	1200 2000

NOTES:

* A C Voltage, RMS value approximately 180° out of phase with the grid voltage.

♦ For a maximum of 30 secs.

* For a maximum of 10 secs.

SPECIAL PURPOSE TUBES—SUBMINIATURE RECEIVING TYPES

10S SYLVANIA ELECTRONIC TUBES

TYPE	CLASS	CONSTRUCTION		EMITTER			CAPACITANCES IN $\mu\mu\text{F}^*$			USE	PLATE VOLTS	SCREEN VOLTS	NEGATIVE GRID VOLTS	PLATE CURRENT MA	SCREEN CURRENT MA	PLATE RESIS. OHMS	AMP. FACTOR OR G_m μMHOS	OHMS LOAD	OUTPUT MW
		BULB SIZE	BASING DIAG.	TYPE	VOLTS	AMPS.	Cgp.	Cin.	Cout										
1AC5	Pentode	3-2	8CP	F	1.25	0.04	Power Amp.	30	30	2.0	0.5	0.1	200,000	450	50,000	5
											45	45	3.0	1.0	0.2	170,000	650	40,000	15
											67.5	67.5	4.5	2.0	0.4	150,000	750	25,000	50
1AD5	Pentode	3-2	8CP	F	1.25	0.04	.009m	1.9	3.0	R F Amp.	30	30	0	0.45	0.16	0.7 Meg.	430
											45	45	0	0.9	0.35	0.7 Meg.	580
											67.5	67.5	0	1.85	0.75	0.7 Meg.	735
1C8	Heptode	3-2	8CN	F	1.25	0.04	0.4m	6.0	5.0	Converter	Same characteristics as Type 1E8.								
1D3	Triode	T-3	8DN	F	1.25	0.30	2.6*	1.0*	1.0*	Amplifier	90	5.0	12.5	8.7
1E8	Heptode	3-2	8CN	F	1.25	0.04	0.4m	6.0	5.0	Converter	30	30	0	0.30	0.8	300,000	115▼
											45	45	0	0.60	1.1	400,000	140▼
											67.5	67.5	0	1.0	1.5	400,000	150▼
1S6	Diode Pentode	3-2	8DA	F	1.25	0.04	Det. Amp.	30	30	0	0.33	0.1	0.5 Meg.	330
											45	45	0	0.75	0.21	0.5 Meg.	475
											67.5	67.5	0	1.6	0.4	0.4 Meg.	600
1T6	Diode Pentode	3-2	8DA	F	1.25	0.04	Det. Amp.	Characteristics Same as Type 1S6.								
1V5	Pentode	3-2	8CP	F	1.25	0.04	Power Amp.	30	30	2.0	0.50	0.10	200,000	450	50,000	5
											45	45	3.0	1.0	0.2	170,000	650	40,000	15
											67.5	67.5	4.5	2.0	0.4	150,000	750	25,000	50
1W5	Pentode	3-2	8CP	F	1.25	0.04	0.01m	2.3	3.5	R F Amp.	30	30	0	0.42	0.16	0.7 Meg.†	430
											67.5	67.5	0	1.85	0.75	0.7 Meg.†	735
										
2B5	Duotriode	3-2	8DP	F	2.4	.13	1.2	0.9	1.9	Amplifier#	90	1.0	2.6	18,700	21.5
					1.2	.26													
6AD4	Triode	3-2	8DK	K	6.3	0.15	1.30	2.80	3.20	Amplifier	100	820▼	1.4	26,000	70
6AK4	Triode	3-1	8DK	K	6.3	0.125	1.3	2.2	2.2	U H F Amp.	200	680▼	9.5	5,300	20

SPECIAL PURPOSE TUBES—SUBMINIATURE RECEIVING TYPES Cont'd

SYLVANIA ELECTRONIC TUBES 115

TYPE	CLASS	CONSTRUCTION		EMITTER			CAPACITANCES IN $\mu\mu F^*$			USE	PLATE VOLTS	SCREEN VOLTS	NEGATIVE GRID VOLTS	PLATE CURRENT MA	SCREEN CURRENT MA	PLATE RESIS. OHMS	AMP. FACTOR OR G_m $\mu\mu\text{MHOS}$	OHMS LOAD	OUTPUT MW
		BULB SIZE	BASING DIAG.	TYPE	VOLTS	AMPS.	Cgp.	Cin.	Cout										
6AZ5	Duodiode	3-1	8DF	K	6.3	0.15	Detector H. W. Rect.	50 A C Volts RMS, 4 Ma Output Current each plate, 8 $\mu\mu\text{f}$ Filter Cap.								
6BA5	Pentode	3-2	8DY	K	6.3	0.15	0.19	4.0	6.5	Audio Amp.	100	100	270▼	4.8	1.25	150,000	3,300
†6BF7W	Duotriode	3-2	8DG	K	6.3	0.3	1.5 1.5	2.0 2.0	1.6 2.0	R F Amp. #	100	100▼	8.0	7,000♦	35
1247	Diode	3-1	1247	F	0.7	0.065	0.8	R F Probe	300 Volts RMS Plate, 0.4 Ma D C Output Current.								
†5636	Pentode	3-1	8DC	K	6.3	0.15	.015m	4.0	3.4	Mixer	100	100	150▼	3.5	5.7	320,000	1,280▼
†5639	Pentode	3-3	8DL	K	6.3	0.45	0.10m	9.5	7.5	Video Amp.	150	100	100▼	21	4.0	50,000	9,000	1,000
†5641	Diode	3-3	6CJ	K	6.3	0.45	H. W. Rect.	117 A C Volts Per Plate, RMS. 45 Ma. D C Output. Capacitor Input to Filter. 235 A C Volts Per Plate, RMS. 45 Ma. D C Output. Capacitor Input to Filter.								
5642	Diode	3-4	5642	F	1.25	0.14	0.6*	H. W. Rect.	Pulse Type Rectifier for Television Service. 10,000 Volts Peak Inverse.								
†5643	Gas Tetrode	3-1	8DD	K	6.3	0.15	0.1	1.7	1.6	Relay Tube	Instantaneous Forward or Inverse Anode Volts = 500 Peak, Average Anode Current = 20 Ma. Max, Averaging Time = 15 Seconds.								
†5644	Gas Diode	3-4	4CN	CK	Voltage Regulator	with Starting Voltages at 130, Operating Voltage 95, Operating Current 5 to 25 Ma.								
†5647	Diode	T-1	5647	K	6.3	0.15	Rectifier Detector	150 A C Volts, RMS. 9 Ma. Output Current. Capacitor Input. Cathode Type Diode for High Frequency Detection.								
†5718	Triode	3-1	8DK	K	6.3	0.15	1.3	2.4	2.4	Amplifier	100 150	150▼ 180▼	8.5 13.0	4,650 4,150	27 27
†5719	Triode	3-1	8DK	K	6.3	0.15	0.7	2.6	2.2	Amplifier	150	680▼	1.7	26,000	70
†5840	Pentode	3-1	8DL	K	6.3	0.15	0.015m	4.2	3.4	R F Amp.	100	100	150▼	7.5	2.4	230,000	5,000
†5896	Duodiode	3-1	8DJ	K	6.3	0.3	F. W. Rect.	150 Volts RMS per Plate, 18 Ma D C Output Current, Plate Supply Impedance = 300 Ohms.								

SPECIAL PURPOSE TUBES—SUBMINIATURE RECEIVING TYPES Cont'd

12 S Y L V A N I A E L E C T R O N I C T U B E S

TYPE	CLASS	CONSTRUCTION		EMITTER			CAPACITANCES IN $\mu\mu F^*$			USE	PLATE VOLTS	SCREEN VOLTS	NEGATIVE GRID	PLATE CURRENT MA	SCREEN CURRENT MA	PLATE RESIS. OHMS	AMP. FACTOR OR G_m $\mu\mu\text{MHOS}$	OHMS LOAD	OUTPUT MW
		BULB SIZE	BASING DIAG.	TYPE	VOLTS	AMPS.	C _{gp}	C _{in}	C _{out}										
†5899	Pentode	3-1	8DL	K	6.3	0.15	.015m	4.4	3.4	R F Amp.	100	100	120▼	7.2	2.2	260,000	4,500
†5902	Pentode	3-3	8DL	K	6.3	0.45	0.20m	6.5	7.5	Power Amp.	110	110	270▼	30	2.2	15,000	4,200	1,000
†5906	Pentode	3-1	8DL	K	26.5	0.045	.015m	4.2	3.4	R F Amp.	100	100	150▼	7.5	2.4	280,000	5,000
†5977	Triode	3-1	8DK	K	6.3	0.15	1.3	2.0	2.2	Amplifier	100	270▼	10.0	3,650	16
†5987	Triode	3-4	8DM	K	6.3	0.45	3.2	3.2	5.0	Amplifier	100	18	9.0	4.1	$G_m = 1,850$	
†6021	DuoTriode	3-1	8DG	K	6.3	0.3	1.4	2.1	...	U H F Amp.*	100	150▼	6.5	6,480	35	C _{out} Sec. 1 = 1.3	
†6110	Duodiode	3-1	8DJ	K	6.3	0.15	U H F Det.	Peak Inverse Voltage = 460 Volts. Peak Anode Current = 26.4 Ma Per Plate.								
†6111	Duotriode	3-1	8DG	K	6.3	0.3	1.5	1.9	0.28 0.32	Med. Mu Amp.*	100	220▼	8.5	4,200	20
†6112	DuoTriode	3-1	8DG	K	6.3	0.3	1.0	1.7	0.23 0.28	High Mu Amp.*	100 150	1,500▼ 820▼	0.8 1.75	38,900 28,000	70 70
†6205	Pentode	3-1	8DC	K	6.3	0.15	.015	4.2	3.4	U H F Amp.	100	100	150▼	7.5	2.4	0.26 Meg.	5,000
†6206	Pentode	3-1	8DC	K	6.3	0.15	.015	4.2	3.4	U H F Amp.	100	100	120▼	7.5	2.0	0.26 Meg.	4,500	Semi-Remote Cutoff	

NOTES:

- * Values given shielded unless indicated with *. Converter tube capacitances given are signal grid to plate; R F Input and mixer output.
- ▼ Conversion Transconductance.
- ◆ Approximate.
- * Per Section.
- † Premium performance type has special mechanical and/or life characteristics. Additional information available on request.
- ▼ Cathode Self Bias Resistor—Ohms.
- m Maximum.
- G_m for pentode and tetrodes, etc.; amplification factor for triodes.

NOTE: Emitter Types—(F) Filament, (K) Unipotential Cathode, (CK) Cold Cathode.

SPECIAL PURPOSE TUBES—RECEIVING AND MISCELLANEOUS TYPES

TYPE	CONSTRUCTION			EMITTER			NOTES (1) (2) CAPACITIES IN $\mu\mu\text{f}$			USE	PLATE VOLTS	SCREEN VOLTS	NEG. GRID VOLTS	PLATE CUR- RENT MA	SCREEN CUR- RENT MA	PLATE RESIST- ANCE OHMS	AMP. FACTOR OR Gm μMHOS	OHMS LOAD FOR STATED POWER OUTPUT	POWER OUTPUT MW
	CLASS	STYLE	BASE	TYPE	VOLTS	AMPS	C _{gp}	C _{in}	C _{out}										
2 X2A (3)	Diode	ST-12	4AB	Cathode	2.5	1.75	H. W. Rectifier	4500 A C Volts per plate RMS, 7.5 Ma Output Current, Capacitor Input to Filter, 12,500 peak Inverse voltage.								
3A4	Pentode	T-5½	7BB	Filament	1.4 2.8	0.20 0.10	0.35m ...	4.8 ...	7.0 ...	Power Amplifier	135 150	90 90	7.5 8.4	14.8 13.3	2.6 2.2	90,000 100,000	1,900 1,900	8,000 8,000	600 700
3A5	Duotriode	T-5½	7BC	Filament	1.4 2.8	0.22 0.11	3.0 ...	1.1 ...	1.9 ...	Amplifier	90 135	2.5 20.0	3.7% 30.0 Push-Pull Class C R F	8,300% Amplifier	15	2,000
5R4GY	Duodiode	ST-16	5T	Filament	5.0	2.0	F. W. Rectifier	900 Volts per plate RMS, 150 Ma D C Output, Capacitor Input to Filter. (Low Loss Base) 950 Volts per plate RMS, 175 Ma D C Output, Choke Input to Filter.								
6AJ5	Pentode	T-5½	7BD	Cathode	6.3	0.175	0.02	4.0	2.8	R F Amplifier	28	28	1.0	2.7	1.0	100,000	2,500	...	R _k =270 Ohms
6AN6	Quadruple Diode	T-5½	7BJ	Cathode	6.3	0.20	Rectifier	75 Volts RMS per plate, 8 Ma D C Output per plate.								
6AS6	Pentode	T-5½	7CM	Cathode	6.3	0.175	0.02	4.0	3.0	R F Amplifier	120	120	2.0	3.6	4.8	...	Gm for G ₁ = 1850; Gm for G ₃ = 810		
6AS7G	Duotriode	ST-16	8BD	Cathode	6.3	2.5	Power Amplifier	135	250▲	125	280	2
6J4	Triode	T-5½	7BQ	Cathode	6.3	0.40	Amplifier	150	200▲	15.0	4,500	55
6J7WGT (3)	Ruggedized version of Type 6J7GT. Data same as Type 6J7GT.																		
6L6GAY	Low Loss Base. Data same as Type 6L6GA.																		
6SA7GT Y	Low Loss Base. Data same as Type 6SA7GT.																		
6SK7GT Y	Low Loss Base. Data same as Type 6SK7GT.																		
6SL7WGT (3)	Ruggedized version of Type 6SL7GT. Data same as Type 6SL7GT.																		
6SN7WGT (3)	Ruggedized version of Type 6SN7GT. Data same as Type 6SN7GT.																		
6SS7GT Y	Pentode	T-9	8N	Cathode	6.3	0.15	R F Amplifier	Low Loss Base. Characteristics same as Type 6SS7.								
6V6GT Y	Low Loss Base. Data same as Type 6V6GT.																		
6 X5WGT (3)	Ruggedized version of Type 6 X5GT. Data same as Type 6 X5GT.																		

SPECIAL PURPOSE TUBES—RECEIVING AND MISCELLANEOUS TYPES Cont'd

145 PENNSYLVANIA ELECTRONIC TUBES

TYPE	CONSTRUCTION			EMITTER			NOTES (1) (2) CAPACITIES IN $\mu\mu\text{f}$			USE	PLATE VOLTS	SCREEN VOLTS	NEG. VOLTS GRID	PLATE CUR- RENT MA	SCREEN CUR- RENT MA	PLATE RESIST- ANCE OHMS	AMP. μ FACTOR OR G_m μMHOS	OHMS LOAD FOR STATED POWER OUTPUT	POWER OUTPUT MW	
	CLASS	STYLE	BASE	TYPE	VOLTS	AMPS	C_{gp}	C_{in}	C_{out}											
7AK7	Pentode	Lock-In	8V	Cathode	6.3	0.8	0.7	12.0	9.5	Computer Tube	150 150 150	90 90 90	0 11 0	40 2.5m 2.0m	21 0.45 60m	11,500 ... $E_{c3}=9.5\text{ V}$	6,500	$E_{c3}=0\text{V}$ $E_{c3}=0\text{V}$	
12AY7	Special low noise audio amp. See complete data section.																			
25A7GT	Diode Pentode	T-9	8F	Cathode	25.0	0.30	H.W. Rectifier Power Amplifier	117 100	Volts per plate RMS, 75 Ma Output Current.			50,000	1,800	4,500	770		
26D6	Heptode	T-5½	7CH	Cathode	26.5	0.07	0.3	7.5	14.0	Converter	100	100	1.5	2.8	8.0	500,000 \downarrow	455 ∇	$R_{k1}=20,000$ $I_{c1}=0.5\text{ Ma}$ $R_{k1}=20,000$ $I_{c1}=0.5\text{ Ma}$ $R_{k1}=20,000$ $I_{c1}=0.1\text{ Ma}$		
											250	100	1.5	3.0	7.8	1.0 Meg. \downarrow	475 ∇			
											26.5	26.5	0.5	0.45	1.6	...	270 ∇			
28D7	Duo-Beam Amplifier	Lock-In	8BS	Cathode	28.0	0.40	Class A2 Amplifier	28	28	390 \blacktriangle *	9.0*	0.7*	R-C Coupled P-P, R-C Coupled P-P Transformer Coupled	4,000*	80*		
											28	28	3.5	25.0	2.0		6,000 \downarrow	225		
											28	28	0	64.0	4.0		1,500 \downarrow	600		
28D7W (3)	Ruggedized version of Type 28D7. Data same as Type 28D7.																			
1222	Beam Pwr. Amp.	ST-14	1222	Cathode	6.3	0.9	Characteristics similar to Type 6L6GA.										
1229	Tetrode	ST-12	4K	Filament	2.0	0.06	Similar to Type 32. Electrometer tube (Low grid current).										
1273	Pentode	Lock-In	8V	Cathode	6.3	0.30	.004m	6.0	6.5	Amplifier	Characteristics same as Type 14C7 (Special Non-Microphonic Tube)									
1280	Pentode	Lock-In	8V	Cathode	12.6	0.15	.004m	6.0	6.5	Amplifier	Characteristics same as Type 14C7 (Special Non-Microphonic Tube)									
5654/ 6AK5W (3)	Pentode	T-5½	7BD	Cathode	6.3	0.175	0.02m	4.0	2.9	R F Amplifier	120	120	200 ∇	7.5	2.5	340,000	5,000	
5679	Duodiode	Lock-In	7CX	Cathode	6.3	0.15	Characteristics same as Type 7A6. For V.T.V.M. use.										
5722	Diode	T-5½	5CB	Filament	4.9	1.6	1.5	Noise Diode	150	...	For noise generator service $I_b=35\text{ Ma Max.}$							
5726/ 6AL5W (3)	Duodiode	T-5½	6BT	Cathode	6.3	0.3	Rectifier	117 A C volts per plate RMS, 9 Ma D C output current per plate.									

SPECIAL PURPOSE TUBES—RECEIVING AND MISCELLANEOUS TYPES Cont'd

PENNSYLVANIA ELECTRONIC TUBES 155

TYPE	CONSTRUCTION			EMITTER			NOTES (1) (2) CAPACITIES IN $\mu\mu\text{f}$			USE	PLATE VOLTS	SCREEN VOLTS	NEG. VOLTS GRID	PLATE CUR- RENT MA	SCREEN CUR- RENT MA	PLATE RESIST- ANCE OHMS	AMP. FACTOR OR Gm μMHOS	LOAD FOR STATED POWER OUTPUT	POWER OUTPUT MW
	CLASS	STYLE	BASE	TYPE	VOLTS	AMPS	C _{gp}	C _{in}	C _{out}										
5749/ 6BA6W (3)	Ruggedized version of Type 6BA6. Data same as Type 6BA6.																		
5751 (3)	Duodiode	T-6½	9A	Cathode	6.3 12.6	.35 .175	1.4★ ...	1.4★	Audio Amplifier	Characteristics same as Type 12A X7. For Reliable Operation. Cout Sec. 1=0.46 $\mu\mu\text{f}$ ★ Cout Sec. 2=0.36 $\mu\mu\text{f}$ ★								
5814A (3)	Duodiode	T-6½	9A	Cathode	12.6 6.3	0.175 0.35	1.5★ ...	1.6★	Amplifier	100 250	8.5 0	11.8 10.5	6,250♦ 7,700♦	19.5 17	Cout Sec. 1=0.5 $\mu\mu\text{f}$ ★ Cout Sec. 2=0.35 $\mu\mu\text{f}$ ★	
5845	Duodiode	T-5½	5CA	Filament	5.0m	0.435	0.8	Control Diode	300m	2.0m	Temperature limited filament emission.				
5931 (3)	Duodiode	T-12	5T	Filament	5.0	3.0	F.W. Rectifier	Characteristics same as Type 5U4G.								
5932 (3)	Beam Amp.	T-12	7S	Cathode	6.3	0.90	Power Amplifier	Characteristics same as Type 6L6G.								
9001	See Condensed Data Section.																		
9002	See Condensed Data Section.																		
9003	See Condensed Data Section.																		
X6030	Diode	Lock-In	X6030	Filament	3.0m	0.6	Noise Diode	90 250 1,400	4.0m 3.0m .535m	

NOTES:

- (1) Values are given shielded unless marked with ★.
- (2) Converter tube capacities given are signal grid to plate; R F Input, mixer output.
- (3) Has special Mechanical and/or life characteristics.
- * Applied through 250,000 ohms.
- m Maximum.
- * Per tube or section.
- ▲ Cathode self bias resistor in ohms.
- ▼ Conversion Transconductance.
- ♦ Approximate.
- ↓ Plate to Plate.

- Gm for pentodes and tetrodes, etc.;
amplification factor for triodes.

SPECIAL PURPOSE TUBES—TRANSMITTING TYPES

16S PENNSYLVANIA ELECTRONIC TUBES

TYPE	CONSTRUCTION			EMITTER		CAPACITANCES			MAXIMUM RATINGS			TYPICAL OPERATION										
	CLASS	STYLE	BASE	VOLTS	AMPS.	C _{gp}	C _{in}	C _{out}	PLATE DISS. WATTS	PLATE CUR-RENT MA	MAX. FREQ. MC	CLASS, OPERATION AND USE*	E _b VOLTS	E _{c2} VOLTS	E _{c1} NEG. VOLTS	I _b MA	I _{c2} MA	I _{c1} MA	P-P LOAD IN OHMS	DRIVING POWER WATTS	POWER OUTPUT WATTS	
2E24	Beam Amp.	T-9	7CL	6.3	0.65	0.11m	8.5	6.5	10	75	...	AB ₂ Amp. and Mod. CCS† AB ₂ Amp. and Mod. ICAS† C (Telegraphy) ICAS C (Telegraphy) ICAS C (Telephony) CCS C (Telephony) ICAS	400	125	15	150▼	26▼	...	7,000 9,000 E _{c3} =0 E _{c3} =0	0.43 0.46 0.21 2.0 0.15 0.16	42 54 27 16.5 13.5 18.0	
									13.5	75	...		500	125	15	150▼	28▼	...				
									13.5	85	125		600	195	50	66	10	3.0				...
									13.5	85	160		350§	170§	50	85	10	3.0				...
									6.7	60	125		400	180	45	50	8.0	2.5				...
									9.0	70	125		500	180	45	54	8.0	2.5				...
2E26	Beam Amp.	T-9	7CK	6.3	0.8	0.20	12.5	7	10	75	...	AB ₂ Amp. and Mod. CCS† AB ₂ Amp. and Mod. ICAS† C (Telegraphy) CCS C (Telegraphy) CCS C (Telegraphy) ICAS C Amp. (Telephony) CCS C Amp. (Telephony) ICAS	400	125	15	150▼	32▼	...	6,200 8,000	0.36 0.36 0.12 0.15 0.17 0.15 0.15	42 54 20 20 27 13.5 18	
									12.5	75	...		500	125	15	150▼	32▼	...				
									10	75	125		400	190	30	75	11	3				...
									10	75	125		500	185	40	60	11	3				...
									13.5	85	125		600	185	45	66	10	3				...
									6.7	60	125		400	160	50	50	7.5	2.5				...
9.0	70	125	500	180	50	54	9.0	2.5	...													
2E30	Beam Amp.	T-5½	7CQ	6.0	0.65	0.2	9.5	6.6	10	60	...	AB ₂ Amp. and Mod. CCS† AB ₂ Amp. and Mod. CCS† C Amp. (Telegraphy) CCS C Amp. (Telegraphy) CCS C Amp. (Telephony)	180	180	22.5	100▼	16▼	...	2,500 3,800 E _{c3} =0 E _{c3} =0 ...	0.23 0.2 0.15 0.2 0.7	7.4 17.0 5.0 7.5 5.0	
									10	60	...		250	250	30	120▼	20▼	...				
									10	60	...		200	200	46	45	10	2.3				...
									10	60	...		250	200	50	50	10	2.5				...
									10	60	...		300	250	70	50	5.0	0.7				...
									10	60	165		300	250	70	50	5.0	0.7				...
3A4	Pentode	T-5½	7BB	1.4 2.8	0.2 0.1	0.20	4.8	4.2	2.0	...	10	C Amp. (Telegraphy)	150	135	26	18.3	6.5	0.13	E _{c3} =0	R _{g2} = 2.300	1.2	
3A5	Duotriode	T-5½	7BC	1.4 2.8	0.22 0.11	3.2	0.9	1.0	1.0	15	40	C Amp. Oscillator†	150	...	35	30	...	5.0	...	0.2	2.2	
801A	Triode	ST-16	4D	7.5	1.25	6.0	4.5	1.5	20	70	...	B Amp. and Mod. CCS† B Amp. and Mod. CCS† B Amp. (Telephony) CCS C Amp. (Telegraphy) CCS C Amp. (Telephony) CCS C Amp. (Telephony) CCS	400	...	50	130▼	6,000 10,000	3 3 2.3 4.0 4.0 4.5	27 45 7.5 25 14 18	
									20	70	...		600	...	75	130▼				
									20	50	60		600	...	75	45▼	...	0.2				...
									20	70	60		600	...	150	65	...	15				...
									13.5	60	60		400	...	150	55	...	15				...
									13.5	60	60		500	...	190	55	...	15				...
807	Beam Amp.	ST-16	5AW	6.3	0.9	This tube type is included in the complete Data Section of the Manual.																
807W	Beam Amp.	T-12	5AW	6.3	0.9	Special mechanical characteristics. Also known as Type 5933. Electrical characteristics same as Type 807.																

SPECIAL PURPOSE TUBES—RECEIVING AND MISCELLANEOUS TYPES Cont'd

TYPE	CONSTRUCTION			EMITTER			NOTES (1) (2) CAPACITIES IN $\mu\mu\text{f}$			USE	PLATE VOLTS	SCREEN VOLTS	NEG. VOLTS GRID	PLATE CUR- RENT MA	SCREEN CUR- RENT MA	PLATE RESIST- ANCE OHMS	AMP. # FACTOR OR G_m μMHOS	LOAD FOR STATED POWER OUTPUT	POWER OUTPUT MW
	CLASS	STYLE	BASE	TYPE	VOLTS	AMPS	C_{gp}	C_{in}	C_{out}										
5749/ 6BA6W (3)	Ruggedized version of Type 6BA6. Data same as Type 6BA6.																		
5751 (3)	Duodiode	T-6½	9A	Cathode	6.3 12.6	.35 .175	1.4★	1.4★	...	Audio Amplifier	Characteristics same as Type 12A X7. For Reliable Operation. Cout Sec. 1=0.46 $\mu\mu\text{f}$ ★ Cout Sec. 2=0.36 $\mu\mu\text{f}$ ★								
5814A (3)	Duotriode	T-6½	9A	Cathode	12.6 6.3	0.175 0.35	1.5★	1.6★	...	Amplifier	100 250	8.5 0	11.8 10.5	6,250♦ 7,700♦	19.5 17	Cout Sec. 1=0.5 $\mu\mu\text{f}$ ★ Cout Sec. 2=0.35 $\mu\mu\text{f}$ ★	
5845	Duodiode	T-5½	5CA	Filament	5.0m	0.435	0.8	Control Diode	300m	2.0m	Temperature limited filament emission.				
5931 (3)	Duodiode	T-12	5T	Filament	5.0	3.0	F.W. Rectifier	Characteristics same as Type 5U4G.								
5932 (3)	Beam Amp.	T-12	7S	Cathode	6.3	0.90	Power Amplifier	Characteristics same as Type 6L6G.								
9001	See Condensed Data Section.																		
9002	See Condensed Data Section.																		
9003	See Condensed Data Section.																		
X6030	Diode	Lock-In	X6030	Filament	3.0m	0.6	Noise Diode	90 250 1,400	4.0m 3.0m .535m	

NOTES:

- (1) Values are given shielded unless marked with ★.
 - (2) Converter tube capacities given are signal grid to plate; R F Input, mixer output.
 - (3) Has special Mechanical and/or life characteristics.
- * Applied through 250,000 ohms.
 - m Maximum.
 - † Per tube or section.
 - ▲ Cathode self bias resistor in ohms.
 - ▼ Conversion Transconductance.
 - ♦ Approximate.
 - ↓ Plate to Plate.

- G_m for pentodes and tetrodes, etc.; amplification factor for triodes.

SPECIAL PURPOSE TUBES—TRANSMITTING TYPES Cont'd

185 PENNSYLVANIA ELECTRONIC TUBES

TYPE	CONSTRUCTION			EMITTER		CAPACITANCES			MAXIMUM RATINGS			TYPICAL OPERATION												
	CLASS	STYLE	BASE	VOLTS	AMPS.	C _{gp}	C _{in}	C _{out}	PLATE DISS. WATTS	PLATE CUR-RENT MA	MAX. FREQ. MC	CLASS, OPERATION AND USE*	E _b VOLTS	E _{c2} VOLTS	E _{c1} NEG. VOLTS	I _b MA	I _{c2} MA	I _{c1} MA	P-P LOAD IN OHMS	DRIVING POWER WATTS	POWER OUTPUT WATTS			
815 Push-Pull	Duo Beam Amplifier	T-16	8BY	12.6	0.8	0.2m	14	8.5	20	150	...	AB ₂ Amp. and Mod. CCS AB ₂ Amp. and Mod. ICAS B Amp. (Telephony) CCS B Amp. (Telephony) ICAS C Amp. (Telegraphy) CCS C Amp. (Telegraphy) ICAS C Amp. (Telephony) CCS C Amp. (Telephony) ICAS	400	125	15	150▼	32▼	6,200	0.36	42			
				6.3	1.6				25	150	...		500	125	15	150▼	32▼				8,000	0.36	54
									20	75	125		400	125	25	75▼	4▼	0.8	10.5
									25	75	125		500	125	25	75▼	3▼	0.7	13
									20	150	125		400	145	45	150	17	4.5				0.23	44
									25	150	125		500	200	45	150	17	3.5				0.18	56
									13.5	125	125		325	165	45	123	16	4				0.20	30
		20	150	125	400	175	45	150	15	3	0.16	45											
816	Diode Mercury Vapor	ST-12	4P	2.5	2.0	Half Wave Rectifier	Max. Peak Inverse Plate Volts = 7500; Max. Peak Plate Current = 500 Ma; Max. Average Plate Current = 125 Ma; Tube Voltage Drop 15 Volts											
829B Push-Pull	Duo Beam Amplifier	T-16	7BP	6.3	2.25	.12sm	14.5	7.0	30	212	200	C Amp. (Telegraphy) CCS C Amp. (Telegraphy) ICAS C Amp. (Telegraphy) ICAS C Amp. (Telegraphy) CCS C Amp. (Telegraphy) ICAS C Amp. (Telephony) CCS C Amp. (Telephony) ICAS C Amp. (Telephony) ICAS C Amp. (Telephony) ICAS C Amp. (Telephony) CCS C Amp. (Telephony) ICAS	750	200	50	120	34	845	65			
				12.6	1.125				40	212	200		500	200	45	240	32	12			0.7	83	
									40	212	200		750	200	55	160	30	12			0.8	87	
									40	240	200		750	200	55	160	30	12			0.8	87	
									45	240	200		750	200	50	200	34	16			1.1	110	
									21	212	200		600	200	70	112	26	8			0.6	50	
									28	212	200		425	200	60	212	35	11			0.8	63	
									28	212	200		600	200	70	150	30	12			0.9	70	
									28	212	200		600	200	70	150	30	12			0.9	70	
									40	240	200		600	200	80	200	30	15			1.4	85	
832A Push-Pull	Duo Beam Amplifier	T-16	7BP	12.6	0.8	0.05sm	7.5	3.8	15	90	200	C Amp. (Telegraphy) CCS C Amp. (Telegraphy) CCS C Amp. (Telephony) CCS C Amp. (Telephony) CCS	500	200	65	72	14	2.6	0.18	26			
				6.3	1.6				15	90	200		750	200	65	48	15	2.8			0.19	26	
									10	68	200		425	200	60	52	16	2.4			0.15	16	
									10	68	200		600	200	65	36	16	2.6			0.16	17	
866A	Diode Mercury Vapor	ST-19	4P	2.5	5.0	Half Wave Rectifier	Max. Peak Inverse Plate Volts = 10,000; Max. Peak Plate Current = 1.0 Amp.; Max. Average Plate Current = 250 Ma; Tube Voltage Drop = 15 Volts											
872A	Diode Mercury Vapor	T-18	4AT	5.0	7.5	Half Wave Rectifier	Max. Peak Inverse Plate Volts = 10,000; Max. Peak Plate Current = 5.0 Amps.; Max. Average Plate Current = 1250; Tube Voltage Drop = 10 Volts.											

SPECIAL PURPOSE TUBES—TRANSMITTING TYPES

SYLVANIA ELECTRONIC TUBES 19S

TYPE	CONSTRUCTION			EMITTER		CAPACITANCES			MAXIMUM RATINGS			TYPICAL OPERATION											
	CLASS	STYLE	BASE	VOLTS	AMPS	C _{gp}	C _{in}	C _{out}	PLATE DISS. WATTS	PLATE CURR. MA	MAX. FREQ. MC	CLASS, OPERATION AND USE*	E _b VOLTS	E _{c2} VOLTS	E _{r1} NEG. VOLTS	I _b MA	I _{c2} MA	I _{c1} MA	P-P LOAD IN OHMS	DRIVING POWER WATTS	POWER OUTPUT WATTS		
5763	Beam Power Tube	T-6½	9K	6.0	0.75	0.3m	9.5	4.5	8	40	30	C Amp. (Telephony) CCS	250	250	39	40	5.6	1.0	Grid 3 to Cathode at Socket	0.05‡	6.4‡		
									12	50	30	C Amp. (Telephony) ICAS	300	250	42.5	50	6	2.4				0.15‡	10‡
									12	50	50	C Amp. (Telegraphy) CCS	300	250	60	50	5.0	3.0				0.35‡	7‡
									13.5	50	30	C Amp. (Telegraphy) ICAS	350	250	28.5	48.5	6.2	1.6				0.1‡	12‡
									12	50	175	Freq. Multi. (Doubler) CCS	300	250	75	40	4	1				0.6	2.1‡
12	50	175	Freq. Multi. (Tripler) CCS	300	250	100	35	5	1	0.6	1.3‡												
5933	Beam Amp.	T-12	5AW	6.3	0.9	0.2m	12.0	7.0				Same as Type 807W. For operating characteristics see Type 807 in complete data section.											
6146	Beam Power Tube	T-12	7CK	6.3	1.25	0.22m	13.5	8.5	20	125	...	AB ₁ Amp. and Mod. CCS†	600	180	45	200▼	23▼	90‡	7,000	0‡	82‡		
									25	135	...	AB ₁ Amp. and Mod. ICAS†	750	190	50	220▼	26▼	100‡	8,000	0‡	120‡		
									20	125	...	AB ₂ Amp. and Mod. CCS†	600	165	44	207▼	17▼	97‡	6,800	0.2	90		
									25	135	...	AB ₂ Amp. and Mod. ICAS†	750	165	46	240▼	20▼	108‡	7,400	0.04	131		
									13.3	117	60	C Amp. (Telephony) CCS	475	135	77	94	6.4	2.8‡	R _{e2} =51,000	0.3	34		
									16.7	125	60	C Amp. (Telephony) ICAS	600	150	87	112	7.8	3.4‡	R _{e2} =56,000	0.4	52		
									20	140	60	C Amp. (Telegraphy) CCS	600	150	58	112	9	2.8‡	R _{e2} =51,000	0.2	52		
									25	150	60	C Amp. (Telegraphy) ICAS	750	160	62	120	11	3.1‡	R _{e2} =56,000	0.2	70		
25	150	175	C Amp. (Telegraphy) ICAS	400	190	54	150	10.4	2.2‡	R _{e2} =20,000	3.0	35											
6159	V H F Beam Power Tube	T-12	7CK	26.5	0.3	0.22	13.5	8.5				Other characteristics same as Type 6146.											

NOTES: m Maximum.

s Shield.

§ Reduced Ratings for 160 Mc.

† Typical operation values are for 2 tubes.

▼ Grid Resistor—ohms.

* Telephony operation is plate modulated. Key down conditions per tube without amplitude modulation.

▼ Maximum Signal.

‡ Approximate.

* Peak Grid to grid A F Volts.

SPECIAL PURPOSE TUBES—INDUSTRIAL TYPES

HIGH VACUUM AMPLIFIERS

TYPE	FILAMENT		MAX. DIMENSIONS INCHES		MAX. PLATE RATINGS CLASS C R-F POWER AMPLIFIER			DISSIPATION WATTS	MAX. FREQ. FOR FULL INPUT	TRANSCONDUCTANCE MICRO-MHOS	AMPLIFICATION FACTOR	BASING DIAG.
	VOLTS	AMPS.	LENGTH	DIAM.	VOLTS	MA.	INPUT WATTS					
813	10.0	5.0	7½	2⅞	2,000	180	400	100	30	3750	8.5*	5BA
829-B†	6.3	1.125	4⅝	2⅜	750	240	120	40	200	8500	9.0*	829-B
892†	22	60	20⅞	6⅜	15,000	2000	30,000	10,000	1.6		50	892
5736†	6.0	60	7¼	3⅝	5,000	1400	5,000	2,500	60		22 Max.	

* Grid No. 2 to Grid No. 1.
 † Without Modulation.

IGNITRON (Resistance Welder Service)

TYPE	MAX. DIMENSIONS INCHES		RMS SUPPLY VOLTS	MAX. KVA DEMAND AND CORRESPONDING AVERAGE CURRENT		MAX. AVERAGE CURRENT AND CORRESPONDING KVA DEMAND		TYPE COOLING
	LENGTH	DIAM.		KVA	AMPS.	KVA	AMPS.	
5550/681	17⅝	2¼	250 600	300	12.1	100	22.4	Clamp
5551-A	23¾	2¼	250 600	600	30.2	200	56.0	Water
5552-A	27¼	4¼	250 600	1200	75.6	400	140	Water
5553-B/655	31¼	5⅝	250 600	2400	192	800	355	Water

SPECIAL PURPOSE TUBES—INDUSTRIAL TYPES
VACUUM RECTIFIERS (Air-Cooled)

TYPE	FILAMENT		MAX. DIMENSIONS INCHES		MAX. ANODE RATINGS			BASING DIAG.
	VOLTS	AMPS.	LENGTH	DIAM.	PEAK INVERSE VOLTS	PEAK AMPERES	AVERAGE AMPERES	
579-B	2.5	6.0	7 $\frac{1}{16}$	2 $\frac{1}{16}$	20,000	0.270	0.025	579-B

THYRATRONS (Grid Controlled Mercury Vapor Rectifier)

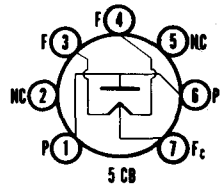
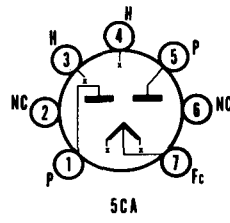
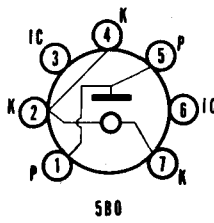
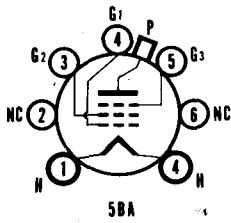
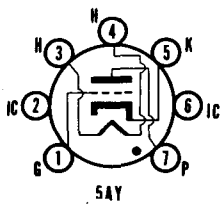
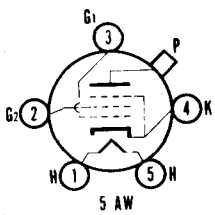
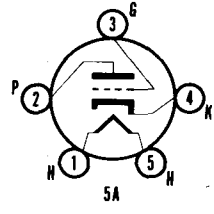
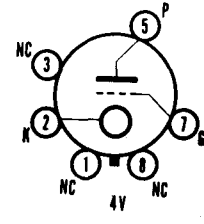
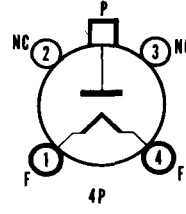
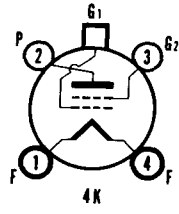
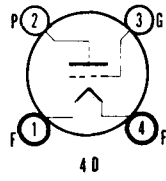
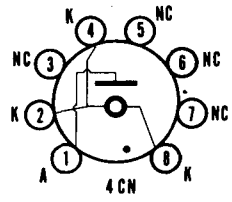
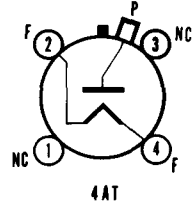
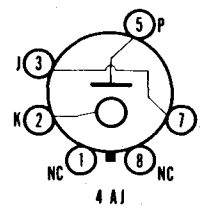
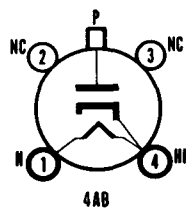
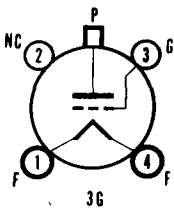
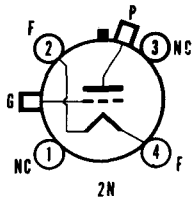
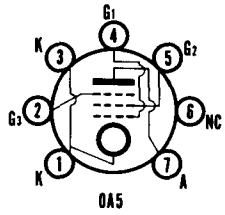
TYPE	FILAMENT		MAX. DIMENSIONS INCHES		NO. OF ELECTRODES	MAX. RATINGS				BASING DIAG.
	VOLTS	AMPS.	LENGTH	DIAM.		PEAK INVERSE VOLTS	PEAK ANODE AMPS.	AVERAGE ANODE AMPS.	TEMP. RANGE CONDENSED MERCURY °C.	
632-B	5.0	5.0	9 $\frac{5}{16}$	2 $\frac{5}{16}$	4	1500	30	2.5	40° to 80°	632-B
672-A	5.0	5.0	8 $\frac{1}{8}$	2 $\frac{3}{16}$	4	2500	40	3.2	40° to 80°	672-A
676	5.0	10.0	11 $\frac{3}{4}$	3 $\frac{3}{16}$	3	2500	40	6.4	40° to 80°	676
677	5.0	10.0	11 $\frac{3}{4}$	3 $\frac{3}{16}$	3	10,000	15	4.0	30° to 50°	677
678	5.0	7.5	11 $\frac{1}{16}$	2 $\frac{9}{16}$	3	15,000	6	1.6	25° to 50°	678

THYRATRONS (Grid Controlled Gas Rectifiers)

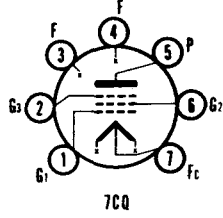
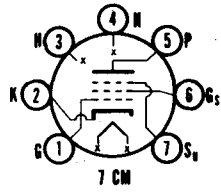
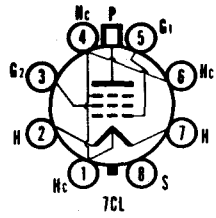
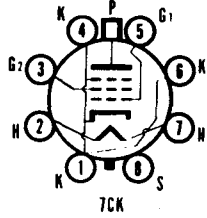
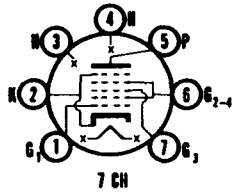
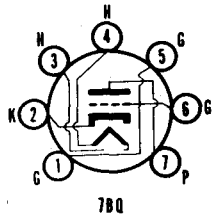
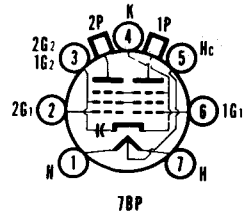
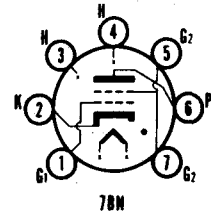
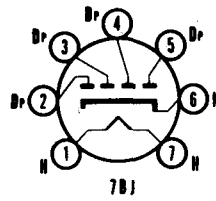
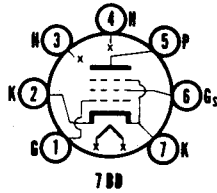
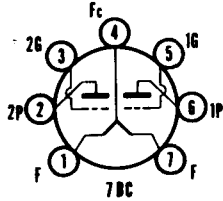
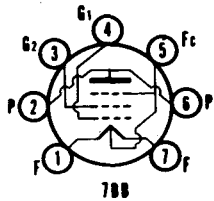
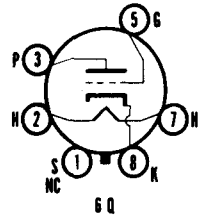
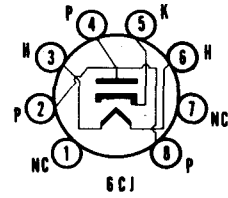
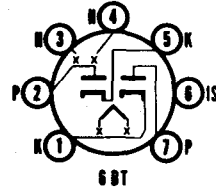
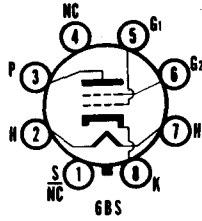
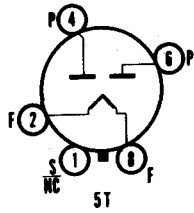
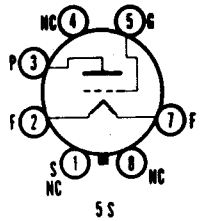
										Ambient	
2050	6.3	0.60	4 $\frac{1}{8}$	1 $\frac{1}{16}$	4	1300	1.0	0.1	-55° to +90°	6BS	
5685	2.5	21.0	9 $\frac{1}{2}$	2	3	1250	77	6.4	-55° to +70°	5685	
5796	2.5	8.5	5 $\frac{1}{4}$	1 $\frac{1}{16}$	3	1500	20	1.6	-55° to +70°	5796	

BASE DIAGRAMS FOR SPECIAL PURPOSE TUBES

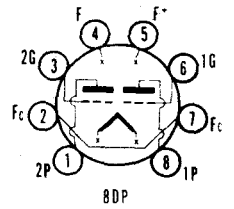
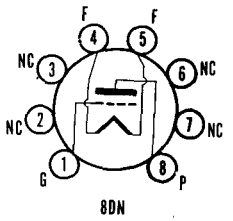
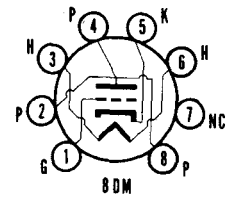
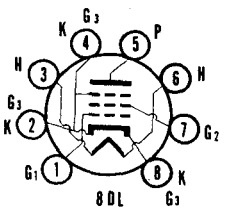
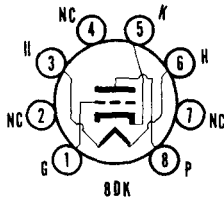
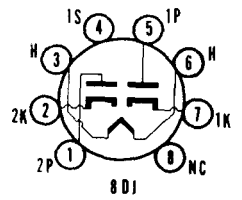
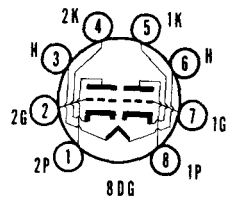
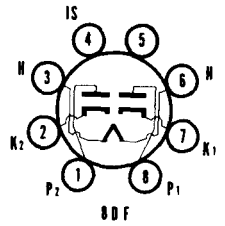
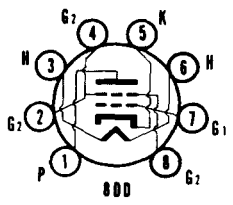
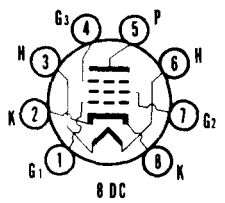
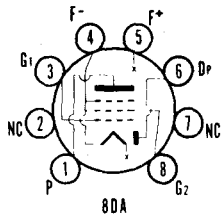
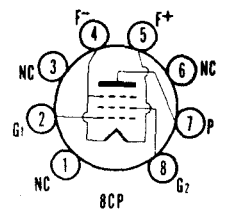
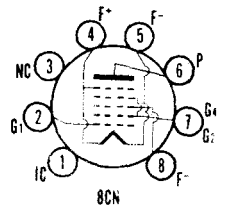
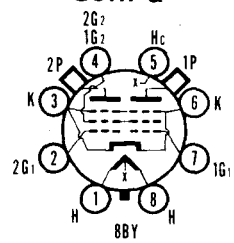
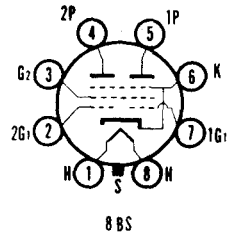
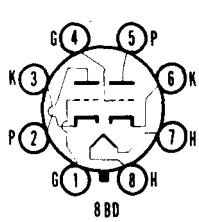
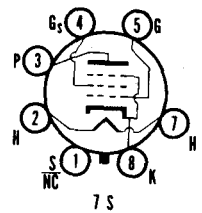
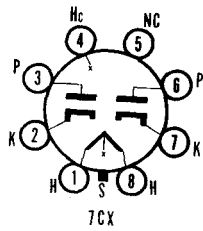
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BASE DIAGRAMS FOR SPECIAL PURPOSE CHART—Cont'd

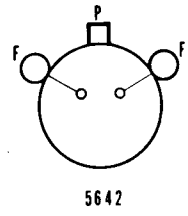
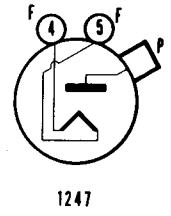
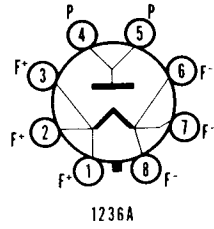
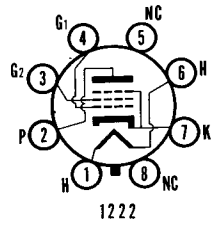
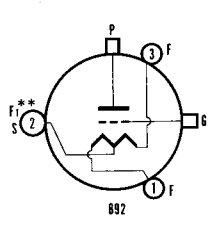
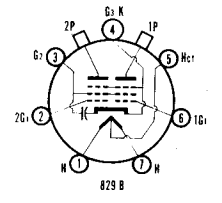
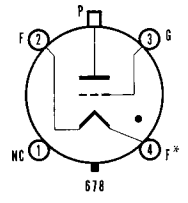
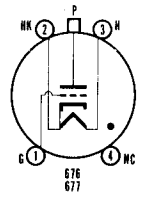
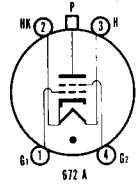
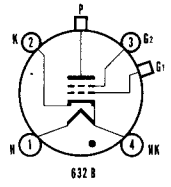
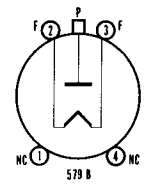
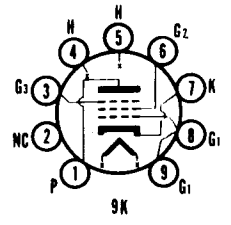
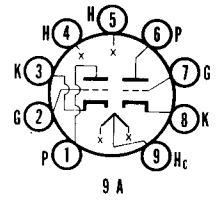
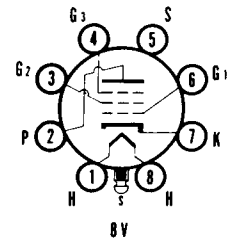
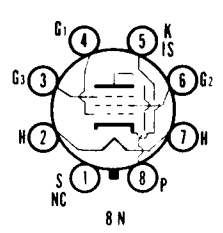
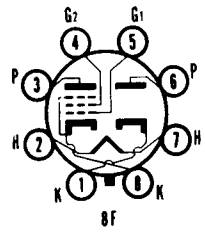
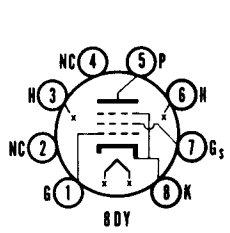


BASE DIAGRAMS FOR SPECIAL PURPOSE CHART—CONT'D



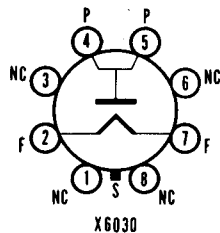
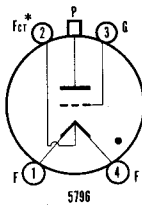
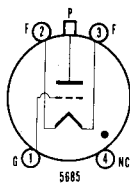
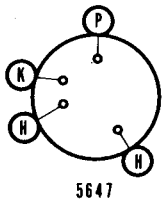
BASE DIAGRAMS FOR SPECIAL PURPOSE CHART—Cont'd

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*Grid and anode return
 **Do not connect two sections in parallel

BASE DIAGRAMS FOR SPECIAL PURPOSE CHART—Cont'd



*Grid and anode return

**Do not connect two sections in parallel